Diode Semiconductor Device - Page 1 of 1



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Inc	closure Material:
Gl	ass
0\	verall Length:
0.3	300 inches
Те	rminal Length:
1.0	000 inches
0\	verall Diameter:
0.4	150 inches
Mo	ounting Method:
Те	rminal
Fe	atures Provided:
He	ermetically sealed case
Se	miconductor Material:
Sil	icon
Vo	Itage Rating In Volts Per Characteristic:
20	0.0 reverse voltage, peak
Cι	irrent Rating Per Characteristic:
3.0	00 amperes forward current, average absolute
Ма	aximum Operating Tempurature Per Measurement Point:
17	5.0 degrees celsius ambient air
Те	rminal Type And Quantity:
2ι	uninsulated wire lead
Sh	nelf Life:
N/a	a
Ur	nit Of Measure:
De	emilitarization:
Nc	
Fii	g:
A1	10a0